

The 2N6453 from MOTOROLA/ST manufacturer is a JFETs (Junction Field Effect) with Precision, Dual Supply, SPST, Analog CMOS Switches. More details for 2N6453 can be seen below.

Categories	晶体管
Manufacturer	MOTOROLA/ST
Veswin Part Number	V1070-2N6453
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Condition	New & Original - Factory Package
Stock Status	In-Stock Inventory
最小起订量	1
Estimated Delivery Time	On May 02 - May 07 (Choose Expedited Shipping)
EDA / CAD Models	2N6453 by SnapEDA
Storage Condition	Dry storage cabinet & Humidity protection package
Vgs Gate Source Breakdown Voltage	- 20 V
Vds Drain Source Breakdown Voltage	10 V
Transistor Polarity	N-Channel
Technology	Si
Pd Power Dissipation	360 mW
Packaging	Reel
Package Case	TO-72-3
Mounting Style	Through Hole
Id Continuous Drain Current	500 pA
Gate Source Cutoff Voltage	- 5 V
Forward Transconductance Min	20 mS
Drain to Source Voltage Vdss	50 mA
Configuration	Single

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